



# TPS54427 4.5-V to 18-V Input, 4-A Output Single Synchronous Step-Down Switcher With Integrated FET

## 1 Features

- D-CAP2™ Mode Enables Fast Transient Response
- Low Output Ripple and Allows Ceramic Output Capacitor
- Wide  $V_{IN}$  Input Voltage Range: 4.5 V to 18 V
- Output Voltage Range: 0.76 V to 7.0 V
- Highly Efficient Integrated FETs Optimized for Lower Duty Cycle Applications
  - 70 mΩ (High Side) and 53 mΩ (Low Side)
- High Efficiency, Less Than 10  $\mu$ A at Shutdown
- High Initial Bandgap Reference Accuracy
- Adjustable Soft Start
- Pre-Biased Soft Start
- 650-kHz Switching Frequency ( $f_{sw}$ )
- Cycle by Cycle Over Current Limit

## 2 Applications

- Wide Range of Applications for Low Voltage System
  - Digital TV Power Supply
  - High Definition Blu-ray Disc™ Players
  - Networking Home Terminal
  - Digital Set Top Box (STB)

## 3 Description

The TPS54427 is an adaptive on-time D-CAP2™ mode synchronous buck converter. The TPS54427 enables system designers to complete the suite of various end equipment's power bus regulators with a cost effective, low component count, low standby current solution.

The main control loop for the TPS54427 uses the D-CAP2™ mode control which provides a fast transient response with no external compensation components.

The TPS54427 also has a proprietary circuit that enables the device to adopt to both low equivalent series resistance (ESR) output capacitors, such as POSCAP or SP-CAP, and ultra-low ESR ceramic capacitors.

The device operates from 4.5-V to 18-V  $V_{IN}$  input. The output voltage can be programmed between 0.76 V and 7 V.

The device also features an adjustable soft start time.

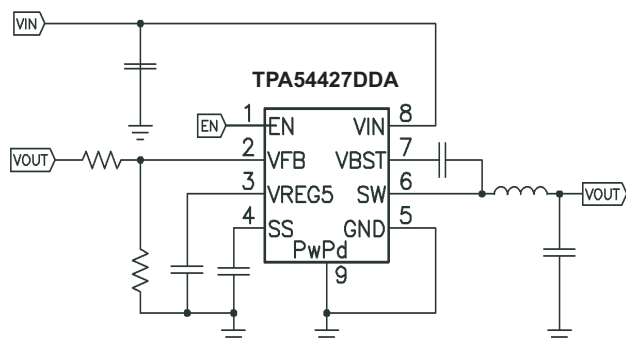
The TPS54427 is available in the 8-pin DDA package and 10-pin DRC, and is designed to operate from  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ .

### Device Information<sup>(1)</sup>

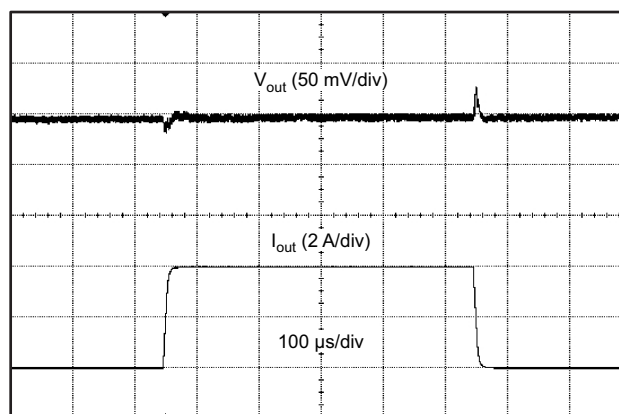
| PART NUMBER | PACKAGE          | BODY SIZE (NOM)   |
|-------------|------------------|-------------------|
| TPS54427    | SO PowerPAD™ (8) | 4.89 mm × 3.90 mm |
|             | VSON (10)        | 3.00 mm × 3.00 mm |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

### Simplified Schematic



### TPS54427 Transient Response



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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

### Changes from Revision B (October 2015) to Revision C Page

- Deleted (SWIFT™) from the data sheet title ..... **1**

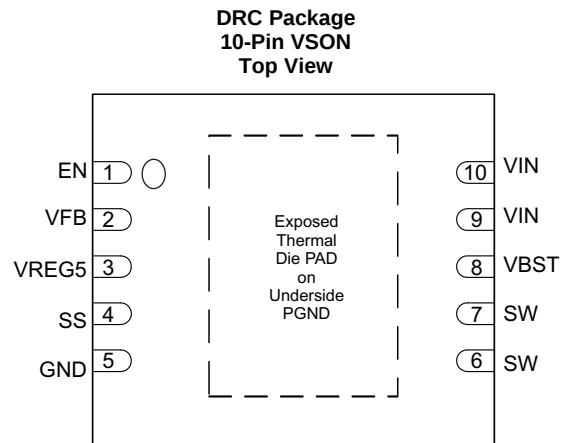
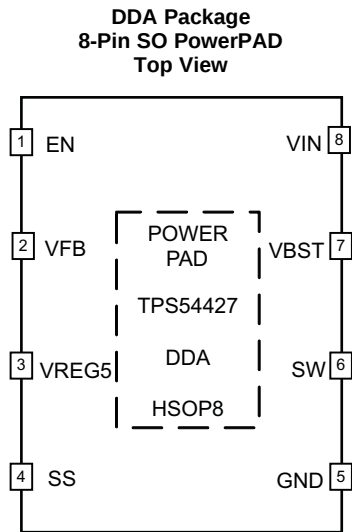
### Changes from Revision A (June 2013) to Revision B Page

- Added *ESD Ratings* table, *Feature Description* section, *Device Functional Modes*, *Application and Implementation* section, *Power Supply Recommendations* section, *Layout* section, *Device and Documentation Support* section, and *Mechanical, Packaging, and Orderable Information* section ..... **1**
- Added the DRC-10 Pin package pin out ..... **3**

### Changes from Original (November 2011) to Revision A Page

- Added "and 10-pin DRC" to the DESCRIPTION ..... **1**
- Added the DRC-10 pin Package to the ORDERING INFORMATION table..... **1**
- Changed the VBST(vs SW) MAX value From: 5.7V to 6V in the ROC table..... **4**
- Changed  $V_{FB}$  input current MAX value From:  $\pm 0.15 \mu A$  To:  $\pm 0.1 \mu A$  ..... **5**
- Added High side switch resistance (DRC) ..... **5**
- Changed [Figure 9](#)..... **7**
- Added [Figure 9](#)..... **7**
- Added [Figure 23](#)..... **17**

## 5 Pin Configuration and Functions



### Pin Functions

| PIN                 |           |           | DESCRIPTION                                                                                                                                                           |
|---------------------|-----------|-----------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME                | DDA       | DRC       |                                                                                                                                                                       |
| EN                  | 1         | 1         | Enable input control. Active high and must be pulled up to enable the device.                                                                                         |
| VFB                 | 2         | 2         | Converter feedback input. Connect to output voltage with feedback resistor divider.                                                                                   |
| VREG5               | 3         | 3         | 5.5 V power supply output. A capacitor (typical 1 $\mu$ F) should be connected to GND. VREG5 is not active when EN is low.                                            |
| SS                  | 4         | 4         | Soft-start control. An external capacitor should be connected to GND.                                                                                                 |
| GND                 | 5         | 5         | Ground pin. Power ground return for switching circuit. Connect sensitive SS and VFB returns to GND at a single point.                                                 |
| SW                  | 6         | 6, 7      | Switch node connection between high-side NFET and low-side NFET.                                                                                                      |
| VBST                | 7         | 8         | Supply input for the high-side FET gate drive circuit. Connect 0.1 $\mu$ F capacitor between VBST and SW pins. An internal diode is connected between VREG5 and VBST. |
| VIN                 | 8         | 9, 10     | Input voltage supply pin.                                                                                                                                             |
| Exposed Thermal Pad | Back side |           | Thermal pad of the package. Must be soldered to achieve appropriate dissipation. Must be connected to GND.                                                            |
|                     |           | Back side | Thermal pad of the package. PGND power ground return of internal low-side FET. Must be soldered to achieve appropriate dissipation.                                   |

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|                                                    |                        | MIN  | MAX | UNIT |
|----------------------------------------------------|------------------------|------|-----|------|
| Input voltage                                      | VIN, EN                | −0.3 | 20  | V    |
|                                                    | VBST                   | −0.3 | 26  | V    |
|                                                    | VBST (10 ns transient) | −0.3 | 28  | V    |
|                                                    | VBST (vs SW)           | −0.3 | 6.5 | V    |
|                                                    | VFB, SS                | −0.3 | 6.5 | V    |
|                                                    | SW                     | −2   | 20  | V    |
|                                                    | SW (10 ns transient)   | −3   | 22  | V    |
| Output voltage                                     | VREG5                  | −0.3 | 6.5 | V    |
|                                                    | GND                    | −0.3 | 0.3 | V    |
| Voltage from GND to thermal pad, V <sub>diff</sub> |                        | −0.2 | 0.2 | V    |
| Operating junction temperature, T <sub>J</sub>     |                        | −40  | 150 | °C   |
| Storage temperature, T <sub>stg</sub>              |                        | −55  | 150 | °C   |

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 6.2 ESD Ratings

|                                            |                                                                                | VALUE | UNIT |
|--------------------------------------------|--------------------------------------------------------------------------------|-------|------|
| V <sub>(ESD)</sub> Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±2000 | V    |
|                                            | Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±500  |      |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.  
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|                 |                                |                        | MIN  | MAX | UNIT |
|-----------------|--------------------------------|------------------------|------|-----|------|
| V <sub>IN</sub> | Supply input voltage           |                        | 4.5  | 18  | V    |
| V <sub>I</sub>  | Input voltage                  | VBST                   | −0.1 | 24  | V    |
|                 |                                | VBST (10 ns transient) | −0.1 | 27  |      |
|                 |                                | VBST(vs SW)            | −0.1 | 6   |      |
|                 |                                | SS                     | −0.1 | 5.7 |      |
|                 |                                | EN                     | −0.1 | 18  |      |
|                 |                                | VFB                    | −0.1 | 5.5 |      |
|                 |                                | SW                     | −1.8 | 18  |      |
|                 |                                | SW (10 ns transient)   | −3   | 21  |      |
|                 |                                | GND                    | −0.1 | 0.1 |      |
| V <sub>O</sub>  | Output voltage                 | VREG5                  | −0.1 | 5.7 | V    |
| I <sub>O</sub>  | Output current                 | I <sub>VREG5</sub>     | 0    | 10  | mA   |
| T <sub>A</sub>  | Operating free-air temperature |                        | −40  | 85  | °C   |
| T <sub>J</sub>  | Operating junction temperature |                        | −40  | 150 | °C   |

## 6.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | TPS54427          |            | UNIT |
|-------------------------------|----------------------------------------------|-------------------|------------|------|
|                               |                                              | DDA [SO PowerPAD] | DRC [VSON] |      |
|                               |                                              | 8 PINS            | 10 PINS    |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 42.1              | 43.2       | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case (top) thermal resistance    | 50.9              | 53.8       | °C/W |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 31.8              | 18.2       | °C/W |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 5                 | 0.6        | °C/W |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 13.5              | 18.3       | °C/W |
| R <sub>θJC(bot)</sub>         | Junction-to-case (bottom) thermal resistance | 7.1               | 4.7        | °C/W |

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report ([SPRA953](#)).

## 6.5 Electrical Characteristics

over operating free-air temperature range, V<sub>IN</sub> = 12 V (unless otherwise noted)

| PARAMETER                                              |                                          | TEST CONDITIONS                                                                              | MIN | TYP | MAX  | UNIT |
|--------------------------------------------------------|------------------------------------------|----------------------------------------------------------------------------------------------|-----|-----|------|------|
| <b>SUPPLY CURRENT</b>                                  |                                          |                                                                                              |     |     |      |      |
| I <sub>VIN</sub>                                       | Operating - non-switching supply current | V <sub>IN</sub> current, T <sub>A</sub> = 25°C, EN = 5 V, V <sub>FB</sub> = 0.8 V            |     | 950 | 1400 | μA   |
| I <sub>VINSDN</sub>                                    | Shutdown supply current                  | V <sub>IN</sub> current, T <sub>A</sub> = 25°C, EN = 0 V                                     |     | 3.0 | 10   | μA   |
| <b>LOGIC THRESHOLD</b>                                 |                                          |                                                                                              |     |     |      |      |
| V <sub>ENH</sub>                                       | EN high-level input voltage              | EN                                                                                           | 1.6 |     |      | V    |
| V <sub>ENL</sub>                                       | EN low-level input voltage               | EN                                                                                           |     |     | 0.6  | V    |
| R <sub>EN</sub>                                        | EN pin resistance to GND                 | V <sub>EN</sub> = 12 V                                                                       | 225 | 450 | 900  | kΩ   |
| <b>V<sub>FB</sub> VOLTAGE AND DISCHARGE RESISTANCE</b> |                                          |                                                                                              |     |     |      |      |
| V <sub>FBTH</sub>                                      | V <sub>FB</sub> threshold voltage        | T <sub>A</sub> = 25°C, V <sub>O</sub> = 1.05 V, continuous mode mode                         | 757 | 765 | 773  | mV   |
|                                                        |                                          | T <sub>A</sub> = -40°C to 85°C, V <sub>O</sub> = 1.05 V, continuous mode mode <sup>(1)</sup> | 751 | 765 | 779  |      |
| I <sub>VFB</sub>                                       | V <sub>FB</sub> input current            | V <sub>FB</sub> = 0.8 V, T <sub>A</sub> = 25°C                                               |     | 0   | ±0.1 | μA   |
| <b>V<sub>REG5</sub> OUTPUT</b>                         |                                          |                                                                                              |     |     |      |      |
| V <sub>VREG5</sub>                                     | V <sub>REG5</sub> output voltage         | T <sub>A</sub> = 25°C, 6.0 V < V <sub>IN</sub> < 18 V, 0 < I <sub>VREG5</sub> < 5 mA         | 5.2 | 5.5 | 5.7  | V    |
| V <sub>LN5</sub>                                       | Line regulation                          | 6 V < V <sub>IN</sub> < 18 V, I <sub>VREG5</sub> = 5 mA                                      |     |     | 25   | mV   |
| V <sub>LD5</sub>                                       | Load regulation                          | 0 mA < I <sub>VREG5</sub> < 5 mA                                                             |     |     | 100  | mV   |
| I <sub>VREG5</sub>                                     | Output current                           | V <sub>IN</sub> = 6 V, V <sub>REG5</sub> = 4.0 V, T <sub>A</sub> = 25°C                      |     | 60  |      | mA   |
| <b>MOSFET</b>                                          |                                          |                                                                                              |     |     |      |      |
| R <sub>DS(on)h</sub>                                   | High side switch resistance (DDA)        | 25°C, V <sub>BST</sub> - SW = 5.5 V                                                          |     | 70  |      | mΩ   |
|                                                        | High side switch resistance (DRC)        |                                                                                              |     | 74  |      |      |
| R <sub>DS(on)l</sub>                                   | Low side switch resistance               | 25°C                                                                                         |     | 53  |      | mΩ   |
| <b>CURRENT LIMIT</b>                                   |                                          |                                                                                              |     |     |      |      |
| I <sub>ocl</sub>                                       | Current limit                            | L out = 1.5 μH <sup>(1)</sup>                                                                | 4.6 | 5.3 | 6.8  | A    |

(1) Not production tested.

## Electrical Characteristics (continued)

over operating free-air temperature range,  $V_{IN} = 12\text{ V}$  (unless otherwise noted)

| PARAMETER             |                            | TEST CONDITIONS                                 | MIN     | TYP  | MAX  | UNIT |
|-----------------------|----------------------------|-------------------------------------------------|---------|------|------|------|
| THERMAL SHUTDOWN      |                            |                                                 |         |      |      |      |
| T <sub>SDN</sub>      | Thermal shutdown threshold | Shutdown temperature <sup>(1)</sup>             | 170     |      |      | °C   |
|                       |                            | Hysteresis <sup>(1)</sup>                       | 35      |      |      |      |
| ON-TIME TIMER CONTROL |                            |                                                 |         |      |      |      |
| t <sub>ON</sub>       | On time                    | V <sub>IN</sub> = 12 V, V <sub>O</sub> = 1.05 V | 150     |      |      | ns   |
| t <sub>OFF(MIN)</sub> | Minimum off time           | T <sub>A</sub> = 25°C, V <sub>FB</sub> = 0.7 V  | 260 310 |      |      | ns   |
| SOFT START            |                            |                                                 |         |      |      |      |
| I <sub>SSC</sub>      | SS charge current          | V <sub>SS</sub> = 1 V                           | 4.2     | 6.0  | 7.8  | μA   |
| I <sub>SSD</sub>      | SS discharge current       | V <sub>SS</sub> = 0.5 V                         | 0.1     | 0.2  |      | mA   |
| UVLO                  |                            |                                                 |         |      |      |      |
| UVLO                  | UVLO threshold             | Wake up V <sub>REG5</sub> voltage               | 3.45    | 3.75 | 4.05 | V    |
|                       |                            | Hysteresis V <sub>REG5</sub> voltage            | 0.19    | 0.32 | 0.45 |      |

## 6.6 Typical Characteristics

$V_{IN} = 12\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

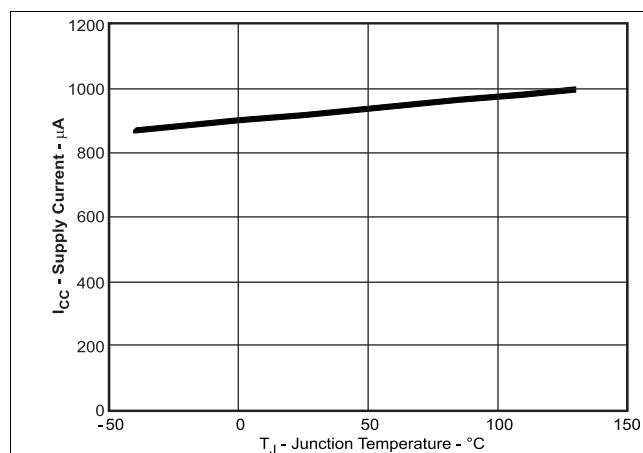


Figure 1. VIN Current vs Junction Temperature

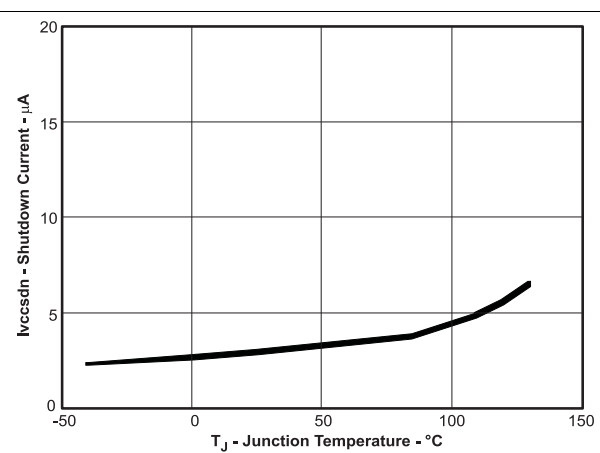


Figure 2. VIN Shutdown Current vs Junction Temperature

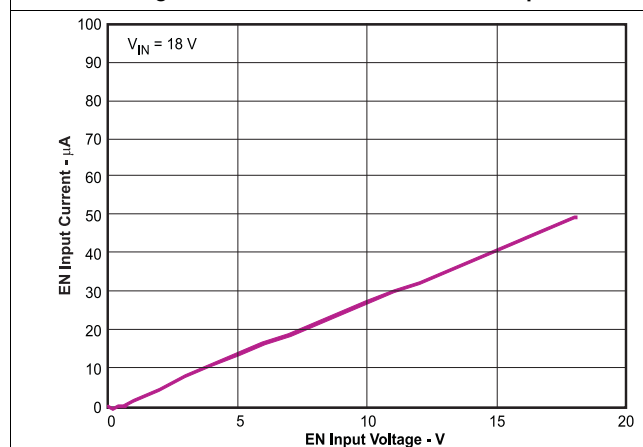


Figure 3. EN Current vs EN Voltage

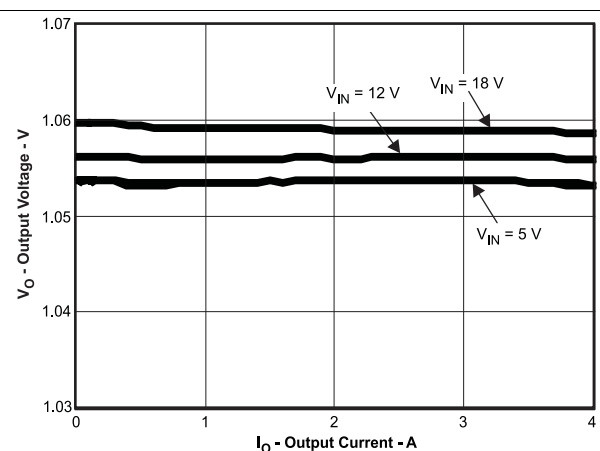


Figure 4. 1.05-V Output Voltage vs Output Current

## Typical Characteristics (continued)

$V_{IN} = 12\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

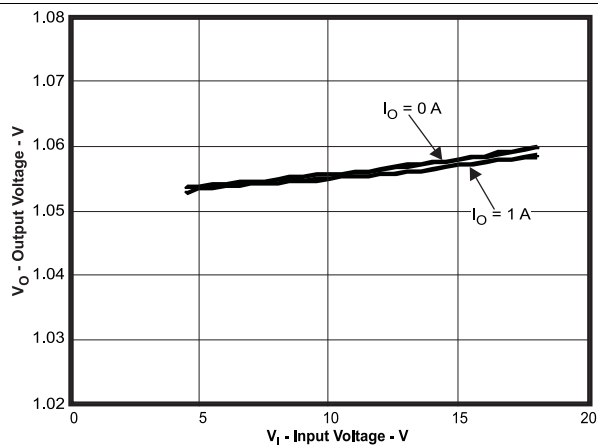


Figure 5. 1.05-V Output Voltage vs  $V_{IN}$  Voltage

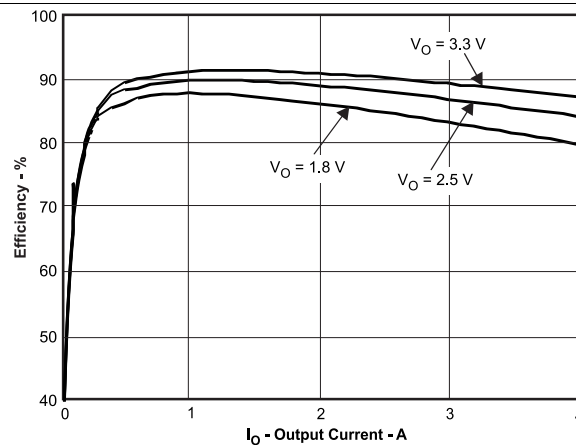


Figure 6. Efficiency vs Output Current

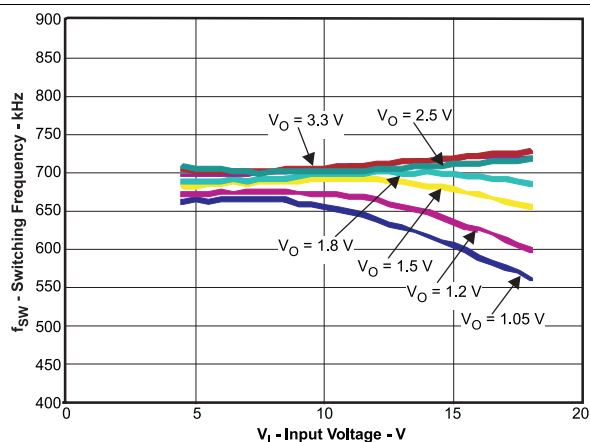


Figure 7. Switching Frequency vs Input Voltage

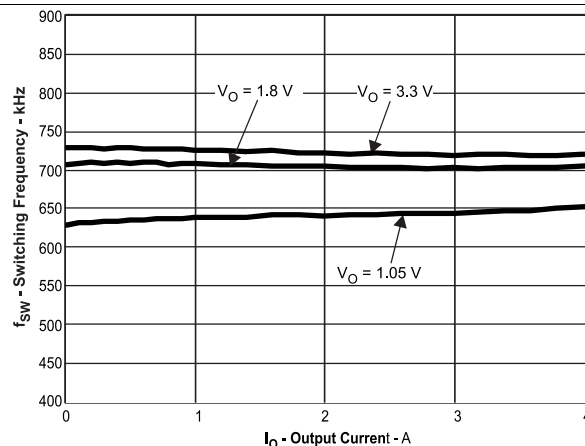


Figure 8. Switching Frequency vs Output Current

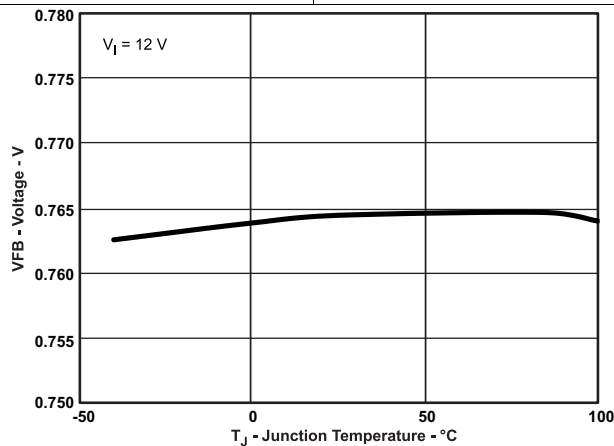


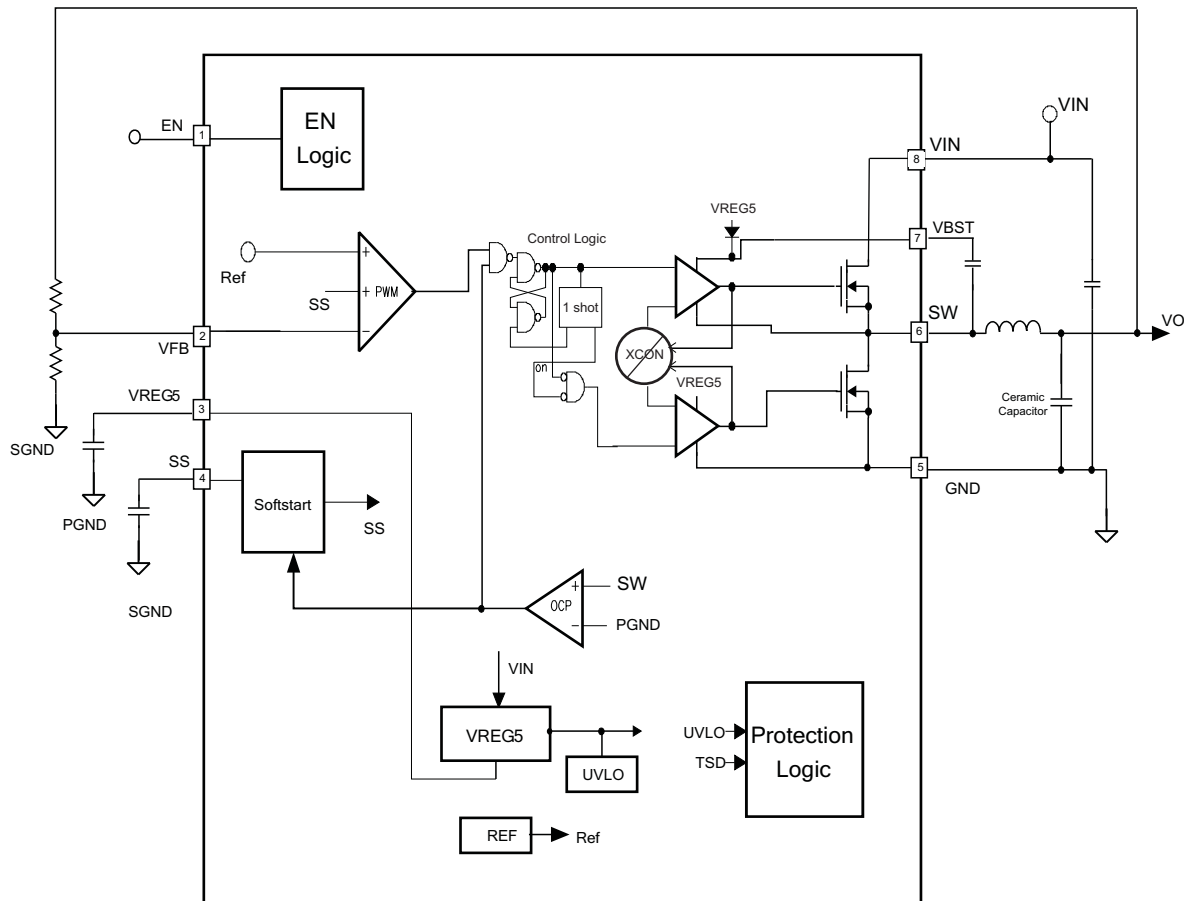
Figure 9. VFB Voltage vs Junction Temperature

## 7 Detailed Description

### 7.1 Overview

The TPS54427 is a 4-A synchronous step-down (buck) converter with two integrated N-channel MOSFETs. It operates using D-CAP2™ mode control. The fast transient response of D-CAP2™ control reduces the output capacitance required to meet a specific level of performance. Proprietary internal circuitry allows the use of low ESR output capacitors including ceramic and special polymer types.

### 7.2 Functional Block Diagram



### 7.3 Feature Description

#### 7.3.1 PWM Operation

The main control loop of the TPS54427 is an adaptive on-time pulse width modulation (PWM) controller that supports a proprietary D-CAP2™ mode control. D-CAP2™ mode control combines constant on-time control with an internal compensation circuit for pseudo-fixed frequency and low external component count configuration with both low ESR and ceramic output capacitors. It is stable even with virtually no ripple at the output.

At the beginning of each cycle, the high-side MOSFET is turned on. This MOSFET is turned off after internal one shot timer expires. This one shot is set by the converter input voltage, VIN, and the output voltage, VO, to maintain a pseudo-fixed frequency over the input voltage range, hence it is called adaptive on-time control. The one-shot timer is reset and the high-side MOSFET is turned on again when the feedback voltage falls below the reference voltage. An internal ramp is added to reference voltage to simulate output ripple, eliminating the need for ESR induced output ripple from D-CAP2™ mode control.

## Feature Description (continued)

### 7.3.2 PWM Frequency and Adaptive On-Time Control

TPS54427 uses an adaptive on-time control scheme and does not have a dedicated on board oscillator. The TPS54427 runs with a pseudo-constant frequency of 650 kHz by using the input voltage and output voltage to set the on-time one-shot timer. The on-time is inversely proportional to the input voltage and proportional to the output voltage, therefore, when the duty ratio is  $V_{OUT}/V_{IN}$ , the frequency is constant.

### 7.3.3 Soft Start and Pre-Biased Soft Start

The soft start function is adjustable. When the EN pin becomes high, 6- $\mu$ A current begins charging the capacitor which is connected from the SS pin to GND. Smooth control of the output voltage is maintained during start up. The equation for the slow start time is shown in Equation 1. VFB voltage is 0.765 V and SS pin source current is 6- $\mu$ A.

$$T_{ss}(ms) = \frac{C6(nF) \times V_{fb} \times 1.1}{I_{ss}(\mu A)} = \frac{C6(nF) \times 0.765 \times 1.1}{6} \quad (1)$$

The TPS54427 contains a unique circuit to prevent current from being pulled from the output during startup if the output is pre-biased. When the soft-start commands a voltage higher than the pre-bias level (internal soft start becomes greater than feedback voltage VFB), the controller slowly activates synchronous rectification by starting the first low side FET gate driver pulses with a narrow on-time. It then increments that on-time on a cycle-by-cycle basis until it coincides with the time dictated by (1-D), where D is the duty cycle of the converter. This scheme prevents the initial sinking of the pre-bias output, and ensure that the out voltage (VO) starts and ramps up smoothly into regulation and the control loop is given time to transition from pre-biased start-up to normal mode operation.

### 7.3.4 Current Protection

The output overcurrent protection (OCP) is implemented using a cycle-by-cycle valley detect control circuit. The switch current is monitored by measuring the low-side FET switch voltage between the SW pin and GND. This voltage is proportional to the switch current. To improve accuracy, the voltage sensing is temperature compensated.

During the on time of the high-side FET switch, the switch current increases at a linear rate determined by  $V_{in}$ ,  $V_{out}$ , the on-time and the output inductor value. During the on time of the low-side FET switch, this current decreases linearly. The average value of the switch current is the load current  $I_{OUT}$ . The TPS54427 constantly monitors the low-side FET switch voltage, which is proportional to the switch current, during the low-side on-time. If the measured voltage is above the voltage proportional to the current limit, an internal counter is incremented per each SW cycle and the converter maintains the low-side switch on until the measured voltage is below the voltage corresponding to the current limit at which time the switching cycle is terminated and a new switching cycle begins. In subsequent switching cycles, the on-time is set to a fixed value and the current is monitored in the same manner. If the over current condition exists for 7 consecutive switching cycles, the internal OCL threshold is set to a lower level, reducing the available output current. When a switching cycle occurs where the switch current is not above the lower OCL threshold, the counter is reset and the OCL limit is returned to the higher value.

There are some important considerations for this type of over-current protection. The load current one half of the peak-to-peak inductor current higher than the over-current threshold. Also when the current is being limited, the output voltage tends to fall as the demanded load current may be higher than the current available from the converter. This may cause the output voltage to fall. When the over current condition is removed, the output voltage will return to the regulated value. This protection is non-latching.

### 7.3.5 UVLO Protection

Undervoltage lock out protection (UVLO) monitors the voltage of the VREG5 pin. When the VREG5 voltage is lower than UVLO threshold voltage, the TPS54427 is shut off. This protection is non-latching.

### 7.3.6 Thermal Shutdown

TPS54427 monitors the temperature of itself. If the temperature exceeds the threshold value (typically 170°C), the device is shut off. This is non-latch protection.

## 7.4 Device Functional Modes

### 7.4.1 Normal Operation

When the input voltage is above the UVLO threshold and the EN voltage is above the enable threshold, the TPS54427 operates in normal switching mode. Normal continuous conduction mode (CCM) occurs when the minimum switch current is above 0 A. In CCM the TPS54427 operates at a quasi-fixed frequency of 650 kHz.

### 7.4.2 Forced CCM Operation

When the TPS54427 is in normal CCM operating mode and switch current falls below 0 A, the device begins operating in forced CCM.

## 8 Application and Implementation

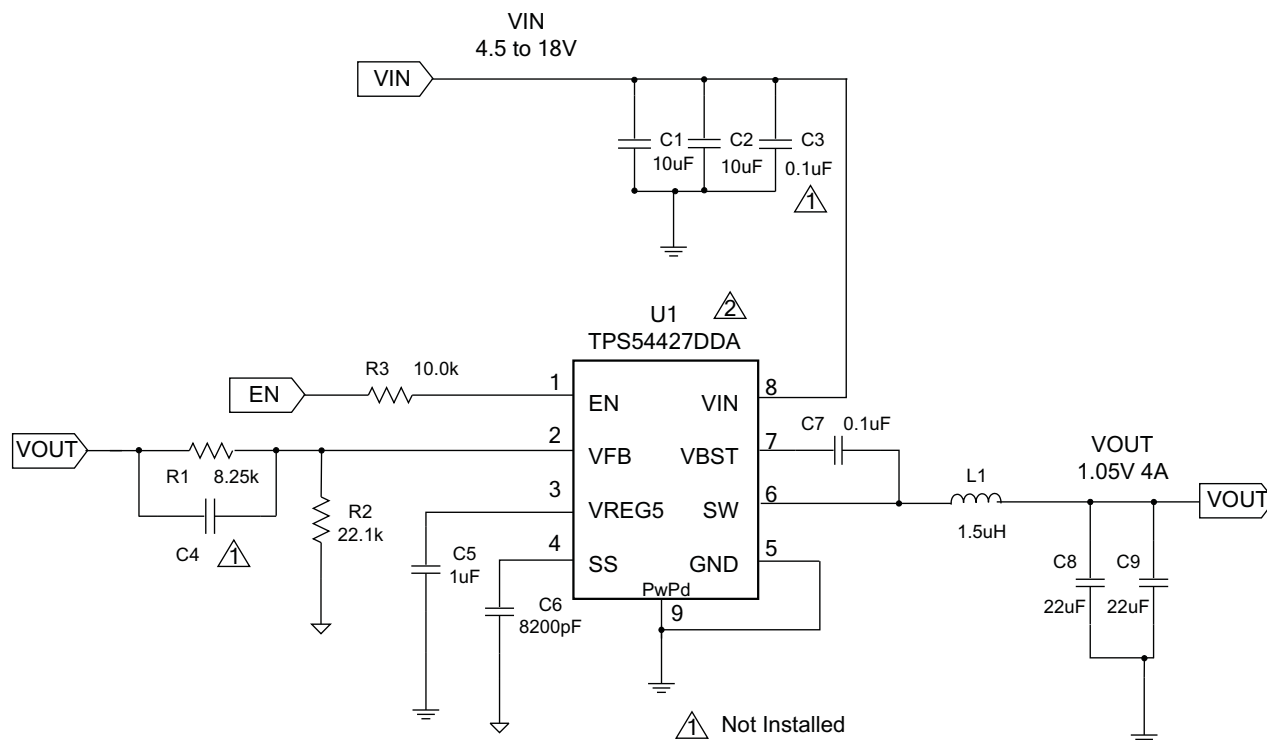
### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

The TPS54427 is used as a step converter that convert an voltage of 4.5 V to 18 V to a lower voltage. WEBENCH® software is available to aid in the design and analysis of circuits.

### 8.2 Typical Application



**Figure 10. Typical Application Schematic**

#### 8.2.1 Design Requirements

Table 1 shows the input and output connections.

**Table 1. TPS54427 Performance Specifications Summary**

| SPECIFICATIONS                | TEST CONDITIONS                             | MIN | TYP  | MAX | UNIT             |
|-------------------------------|---------------------------------------------|-----|------|-----|------------------|
| Input voltage range, $V_{IN}$ |                                             | 4.5 | 12   | 18  | V                |
| Output voltage, $V_{OUT}$     |                                             |     | 1.05 |     | V                |
| Operating frequency           | $V_{IN} = 12\text{ V}$ , $I_O = 4\text{ A}$ |     | 650  |     | kHz              |
| Output current range          |                                             | 0   |      | 4   | A                |
| Output ripple voltage         | $V_{IN} = 12\text{ V}$ , $I_O = 4\text{ A}$ |     | 15   |     | mV <sub>PP</sub> |

## 8.2.2 Detailed Design Procedure

To begin the design process, you must know a few application parameters:

- Input voltage range
- Output voltage
- Output current
- Output voltage ripple
- Input voltage ripple

### 8.2.2.1 Output Voltage Resistors Selection

The output voltage is set with a resistor divider from the output node to the VFB pin. It is recommended to use 1% tolerance or better divider resistors. Start by using [Equation 2](#) to calculate  $V_{OUT}$ .

To improve efficiency at very light loads consider using larger value resistors, too high of resistance will be more susceptible to noise and voltage errors from the VFB input current will be more noticeable.

$$V_{OUT} = 0.765 \times \left( 1 + \frac{R1}{R2} \right) \quad (2)$$

### 8.2.2.2 Output Filter Selection

The output filter used with the TPS54427 is an LC circuit. This LC filter has double pole at:

$$F_P = \frac{1}{2\pi \sqrt{L_{OUT} \times C_{OUT}}} \quad (3)$$

At low frequencies, the overall loop gain is set by the output set-point resistor divider network and the internal gain of the TPS54427. The low frequency phase is 180 degrees. At the output filter pole frequency, the gain rolls off at a –40 dB per decade rate and the phase drops rapidly. D-CAP2™ introduces a high frequency zero that reduces the gain roll off to –20 dB per decade and increases the phase to 90 degrees one decade above the zero frequency. The inductor and capacitor selected for the output filter must be selected so that the double pole of [Equation 3](#) is located below the high frequency zero but close enough that the phase boost provided by the high frequency zero provides adequate phase margin for a stable circuit. To meet this requirement use the values recommended in [Table 2](#).

**Table 2. Recommended Component Values**

| OUTPUT VOLTAGE (V) | R1 (kΩ) | R2 (kΩ) | C4 (pF) <sup>(1)</sup> | L1 (μH) | C8 + C9 (μF) |
|--------------------|---------|---------|------------------------|---------|--------------|
| 1                  | 6.81    | 22.1    |                        | 1.5     | 22 - 68      |
| 1.05               | 8.25    | 22.1    |                        | 1.5     | 22 - 68      |
| 1.2                | 12.7    | 22.1    |                        | 1.5     | 22 - 68      |
| 1.5                | 21.5    | 22.1    |                        | 1.5     | 22 - 68      |
| 1.8                | 30.1    | 22.1    | 5 - 22                 | 2.2     | 22 - 68      |
| 2.5                | 49.9    | 22.1    | 5 - 22                 | 2.2     | 22 - 68      |
| 3.3                | 73.2    | 22.1    | 5 - 22                 | 2.2     | 22 - 68      |
| 5                  | 124     | 22.1    | 5 - 22                 | 3.3     | 22 - 68      |
| 6.5                | 165     | 22.1    | 5 - 22                 | 3.3     | 22 - 68      |

(1) Optional

For higher output voltages at or above 1.8 V, additional phase boost can be achieved by adding a feed forward capacitor (C4) in parallel with R1.

The inductor peak-to-peak ripple current, peak current and RMS current are calculated using [Equation 4](#), [Equation 5](#) and [Equation 6](#). The inductor saturation current rating must be greater than the calculated peak current and the RMS or heating current rating must be greater than the calculated RMS current. Use 650 kHz for  $f_{SW}$ .

Use 650 kHz for  $f_{SW}$ . Make sure the chosen inductor is rated for the peak current of [Equation 5](#) and the RMS current of [Equation 6](#).

$$I_{P-P} = \frac{V_{OUT}}{V_{IN(MAX)}} \times \frac{V_{IN(MAX)} - V_{OUT}}{L_O \times f_{SW}} \quad (4)$$

$$I_{PEAK} = I_O + \frac{I_{P-P}}{2} \quad (5)$$

$$I_{LO(RMS)} = \sqrt{I_O^2 + \frac{1}{12} I_{P-P}^2} \quad (6)$$

For this design example, the calculated peak current is 4.51 A and the calculated RMS current is 4.01 A. The inductor used is a TDK SPM6530-1R5M100 with a peak current rating of 11.5 A and an RMS current rating of 11 A.

The capacitor value and ESR determines the amount of output voltage ripple. The TPS54427 is intended for use with ceramic or other low ESR capacitors. Recommended values range from 22µF to 68µF. Use Equation 7 to determine the required RMS current rating for the output capacitor.

$$I_{CO(RMS)} = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{\sqrt{12} \times V_{IN} \times L_O \times f_{SW}} \quad (7)$$

For this design two TDK C3216X5R0J226M 22µF output capacitors are used. The typical ESR is 2 mΩ each. The calculated RMS current is 0.286A and each output capacitor is rated for 4A.

### 8.2.2.3 Input Capacitor Selection

The TPS54427 requires an input decoupling capacitor and a bulk capacitor is needed depending on the application. A ceramic capacitor over 10 µF is recommended for the decoupling capacitor. An additional 0.1 µF capacitor (C3) from pin 8 to ground is optional to provide additional high frequency filtering. The capacitor voltage rating needs to be greater than the maximum input voltage.

### 8.2.2.4 Bootstrap Capacitor Selection

A 0.1-µF ceramic capacitor must be connected between the VBST to SW pin for proper operation. It is recommended to use a ceramic capacitor.

### 8.2.2.5 VREG5 Capacitor Selection

A 1-µF ceramic capacitor must be connected between the VREG5 to GND pin for proper operation. It is recommended to use a ceramic capacitor.

## 8.2.3 Application Curves

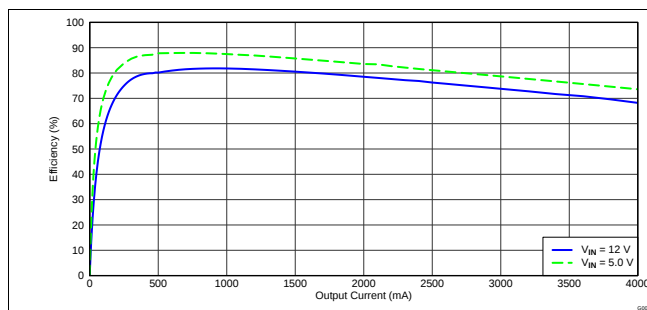


Figure 11. TPS54427 Efficiency

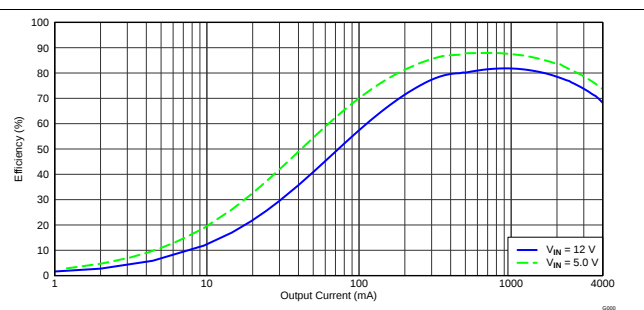
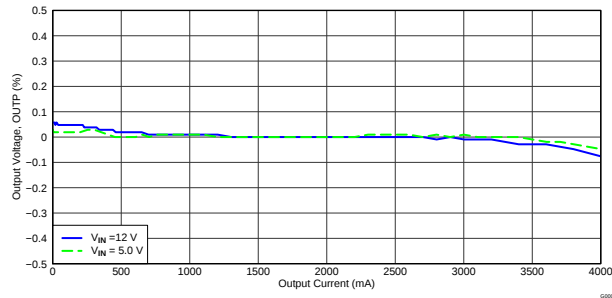
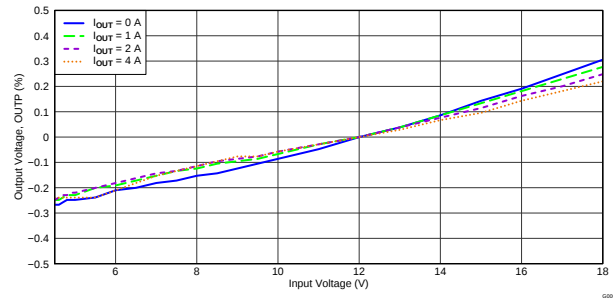
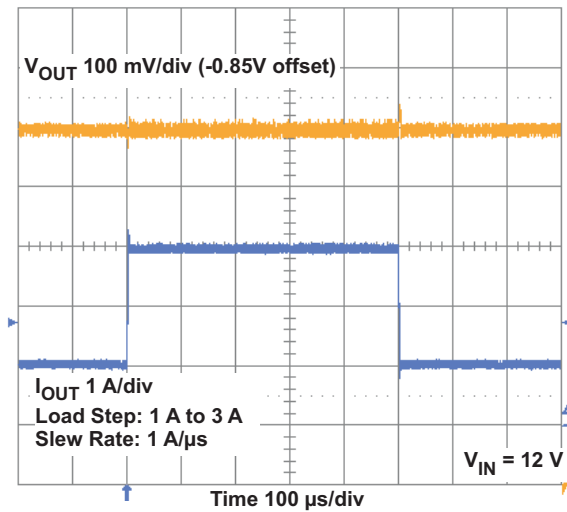
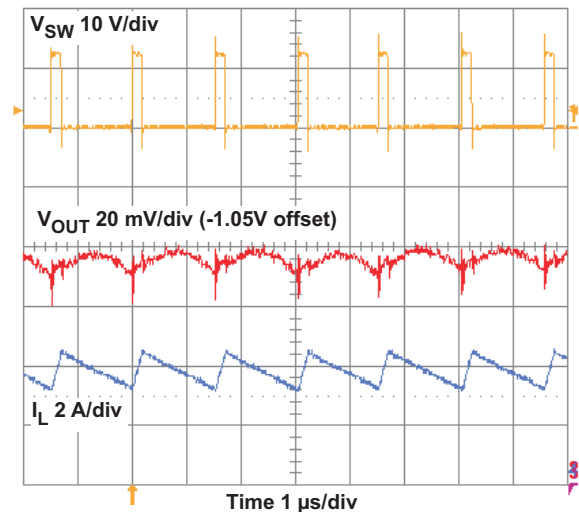
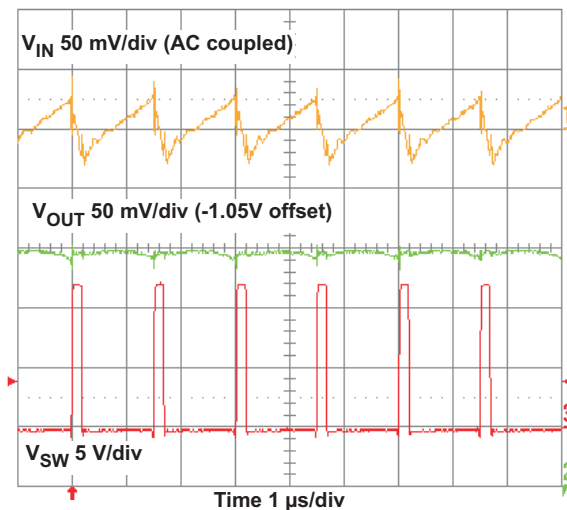
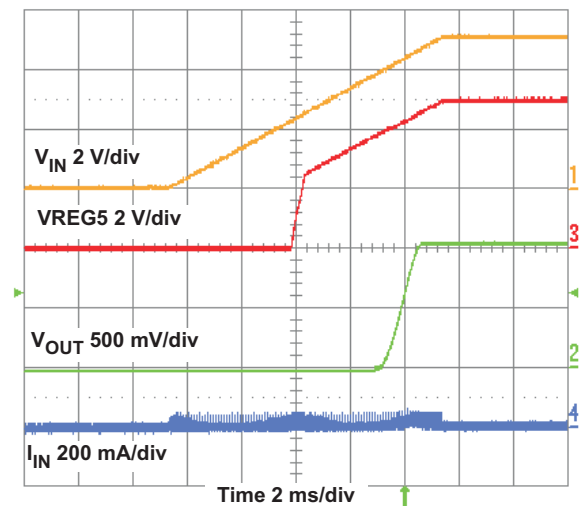


Figure 12. TPS54427 Light-Load Efficiency

**TPS54427**

SLVSB43C –NOVEMBER 2011–REVISED FEBRUARY 2016

[www.ti.com](http://www.ti.com)

**Figure 13. TPS54427 Load Regulation,  $V_{IN} = 5\text{ V}$  and  $V_{IN} = 12\text{ V}$ .**

**Figure 14. TPS54427 Line Regulation**

**Figure 15. TPS54427 Load Transient Response**

**Figure 16. TPS54427 Output Voltage Ripple**

**Figure 17. TPS54427 Input Voltage Ripple**

**Figure 18. TPS54427 Start-Up Relative to  $V_{IN}$**

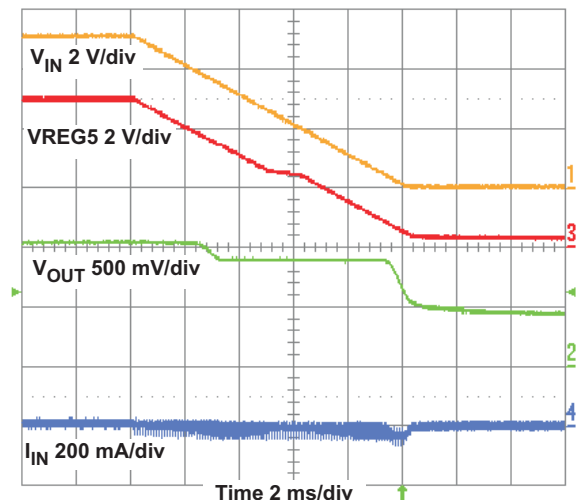


Figure 19. TPS54427 Shut-down Relative to  $V_{IN}$

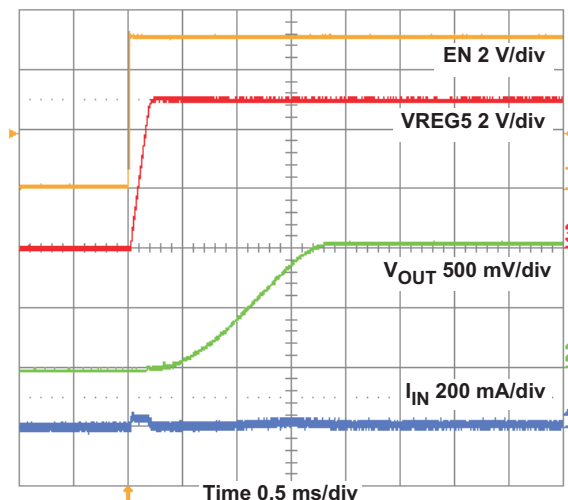


Figure 20. TPS54427 Start-Up Relative to EN

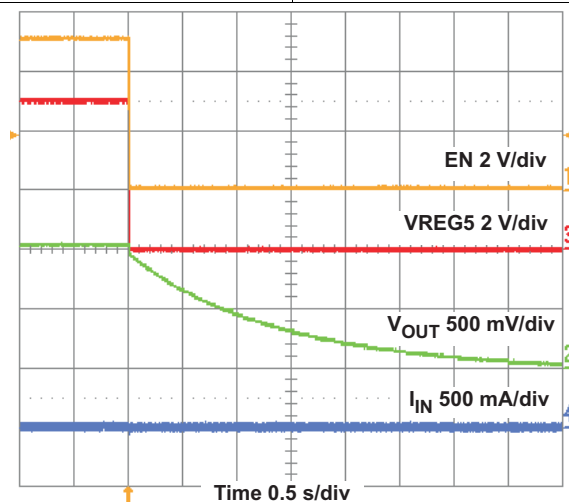


Figure 21. TPS54427 Shut-down Relative to EN

## 9 Power Supply Recommendations

The TPS54427 is designed to operate from input supply voltage in the range of 4.5 V to 18 V. Buck converters require the input voltage to be higher than the output voltage. In this case the maximum recommended operating duty cycle is 65%. Using that criteria, the minimum recommended input voltage is  $V_o/0.65$ .

## 10 Layout

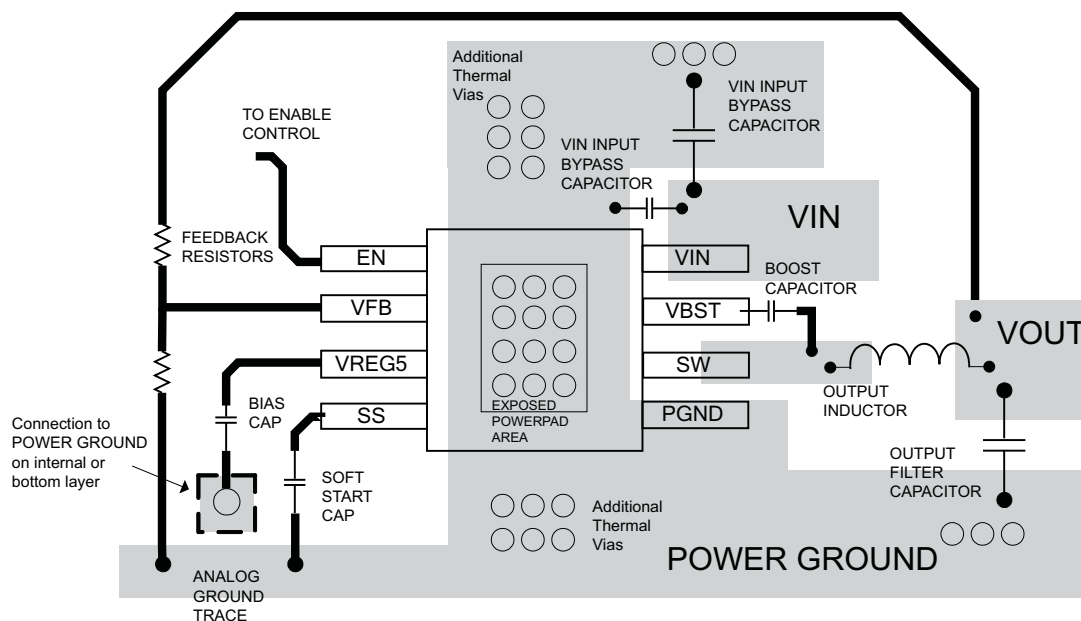
### 10.1 Layout Guidelines

1. The TPS54427 can supply relatively large current up to 4A. So heat dissipation may be a concern. The top side area adjacent to the TPS54427 should be filled with ground as much as possible to dissipate heat.
2. The bottom side area directly below the IC should have a dedicated ground area. It should be directly connected to the thermal pad of the using vias as shown. The ground area should be as large as practical. Additional internal layers can be dedicated as ground planes and connected to vias as well.
3. Keep the input switching current loop as small as possible.
4. Keep the SW node as physically small and short as possible to minimize parasitic capacitance and inductance and to minimize radiated emissions. Kelvin connections should be brought from the output to the feedback pin of the device.

## Layout Guidelines (continued)

5. Keep analog and non-switching components away from switching components.
6. Make a single point connection from the signal ground to power ground.
7. Do not allow switching current to flow under the device.
8. Keep the pattern lines for VIN and PGND broad.
9. Exposed pad of device must be connected to PGND with solder.
10. VREG5 capacitor should be placed near the device, and connected PGND.
11. Output capacitor should be connected to a broad pattern of the PGND.
12. Voltage feedback loop should be as short as possible, and preferably with ground shield.
13. Lower resistor of the voltage divider which is connected to the VFB pin should be tied to SGND.
14. Providing sufficient via is preferable for VIN, SW and PGND connection.
15. PCB pattern for VIN, SW, and PGND should be as broad as possible.
16. VIN Capacitor should be placed as near as possible to the device.

## 10.2 Layout Examples



**Figure 22. TPS54427 Layout**

## Layout Examples (continued)

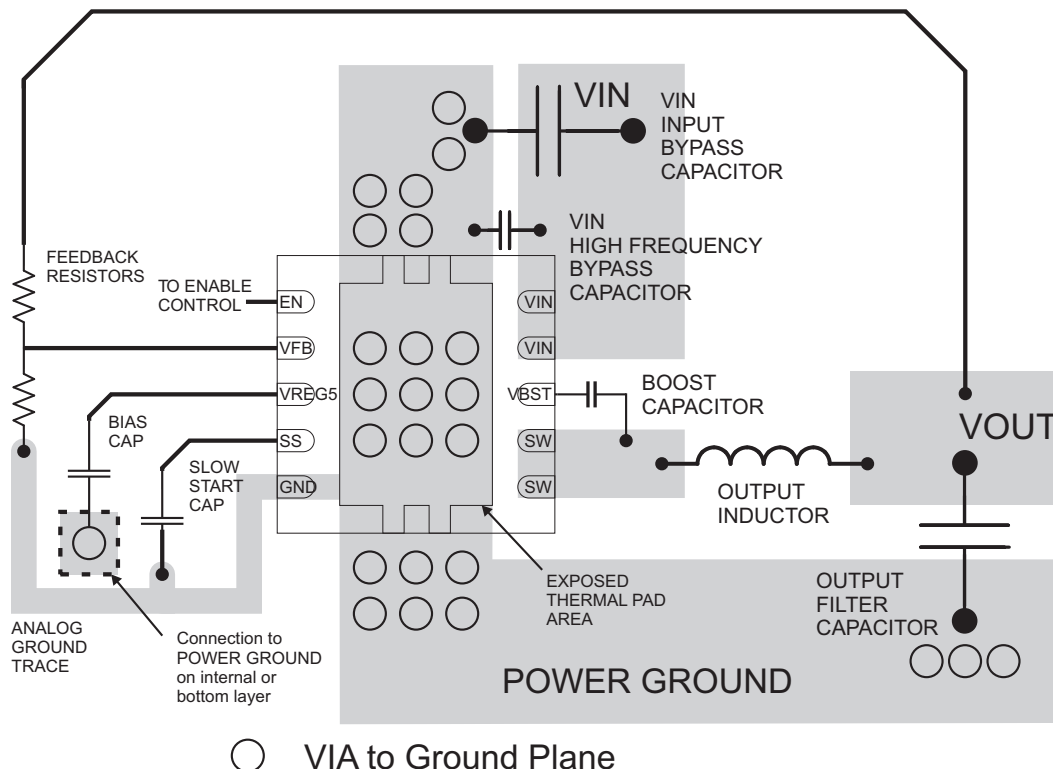


Figure 23. PCB Layout for the DRC Package

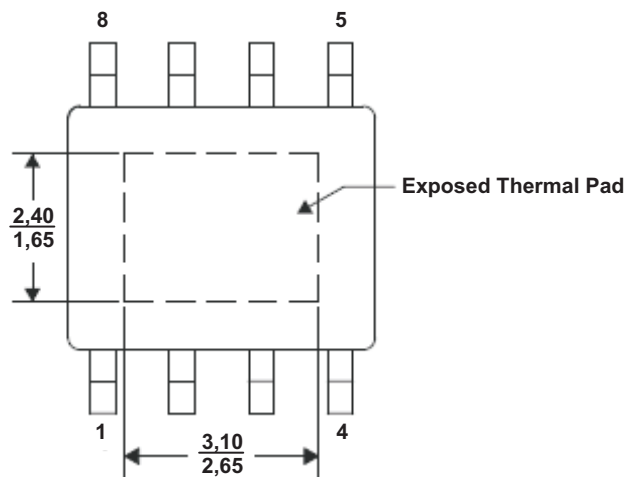
## 10.3 Thermal Considerations

This 8-pin DDA package incorporates an exposed thermal pad that is designed to be directly to an external heatsink. The thermal pad must be soldered directly to the printed board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the exposed thermal pad and how to use the advantage of its heat dissipating abilities, refer to Technical Brief, *PowerPAD™ Thermally Enhanced Package*, [SLMA002](#) and Application Brief, *PowerPAD™ Made Easy*, [SLMA004](#).

The exposed thermal pad dimensions for this package are shown in the following illustration.

## Thermal Considerations (continued)



**Figure 24. Thermal Pad Dimensions**

## 11 Device and Documentation Support

### 11.1 Device Support

#### 11.1.1 Third-Party Products Disclaimer

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#### 11.1.2 Design Support

WEBENCH™ software uses an iterative design procedure and accesses comprehensive databases of components. For more details, go to [www.ti.com/webench](http://www.ti.com/webench).

### 11.2 Documentation Support

#### 11.2.1 Related Documentation

For related documentation see the following:

- *PowerPAD™ Thermally Enhanced Package*, [SLMA002](#)
- *PowerPAD™ Made Easy*, [SLMA004](#)

### 11.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 11.4 Trademarks

D-CAP2, PowerPAD, E2E are trademarks of Texas Instruments.  
WEBENCH is a registered trademark of Texas Instruments.  
Blu-ray Disc is a trademark of Blu-ray Disc Association.  
All other trademarks are the property of their respective owners.

### 11.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 11.6 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2)            | Lead/Ball Finish<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|--------------------|------|----------------|----------------------------|-------------------------|----------------------|--------------|-------------------------|-------------------------|
| TPS54427DDA      | ACTIVE        | SO PowerPAD  | DDA                | 8    | 75             | Green (RoHS<br>& no Sb/Br) | NIPDAU   SN             | Level-2-260C-1 YEAR  | -40 to 85    | 54427                   | <a href="#">Samples</a> |
| TPS54427DDAR     | ACTIVE        | SO PowerPAD  | DDA                | 8    | 2500           | Green (RoHS<br>& no Sb/Br) | NIPDAU   SN             | Level-2-260C-1 YEAR  | -40 to 85    | 54427                   | <a href="#">Samples</a> |
| TPS54427DRCR     | ACTIVE        | VSON         | DRC                | 10   | 3000           | Green (RoHS<br>& no Sb/Br) | NIPDAU                  | Level-2-260C-1 YEAR  | -40 to 85    | 54427                   | <a href="#">Samples</a> |
| TPS54427DRCT     | ACTIVE        | VSON         | DRC                | 10   | 250            | Green (RoHS<br>& no Sb/Br) | NIPDAU                  | Level-2-260C-1 YEAR  | -40 to 85    | 54427                   | <a href="#">Samples</a> |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

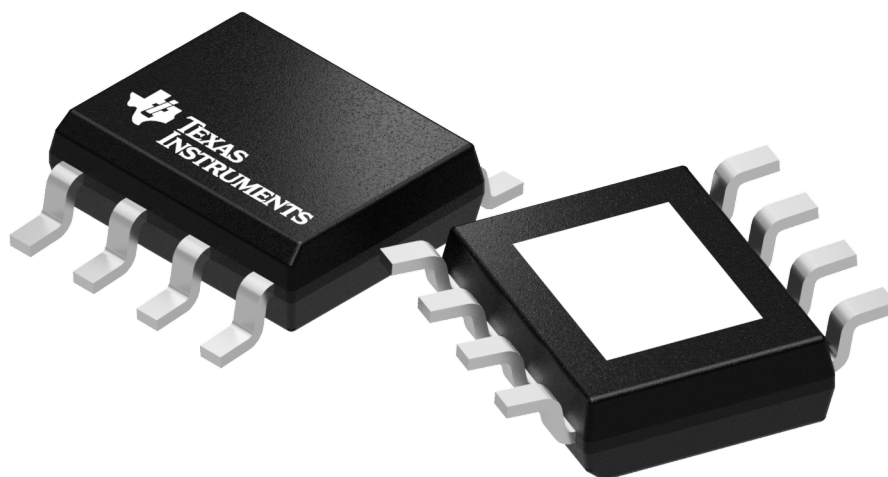
| Device       | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPS54427DDAR | SO Power PAD | DDA             | 8    | 2500 | 330.0              | 12.8               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| TPS54427DRCR | VSON         | DRC             | 10   | 3000 | 330.0              | 12.4               | 3.3     | 3.3     | 1.1     | 8.0     | 12.0   | Q2            |
| TPS54427DRCT | VSON         | DRC             | 10   | 250  | 180.0              | 12.4               | 3.3     | 3.3     | 1.1     | 8.0     | 12.0   | Q2            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

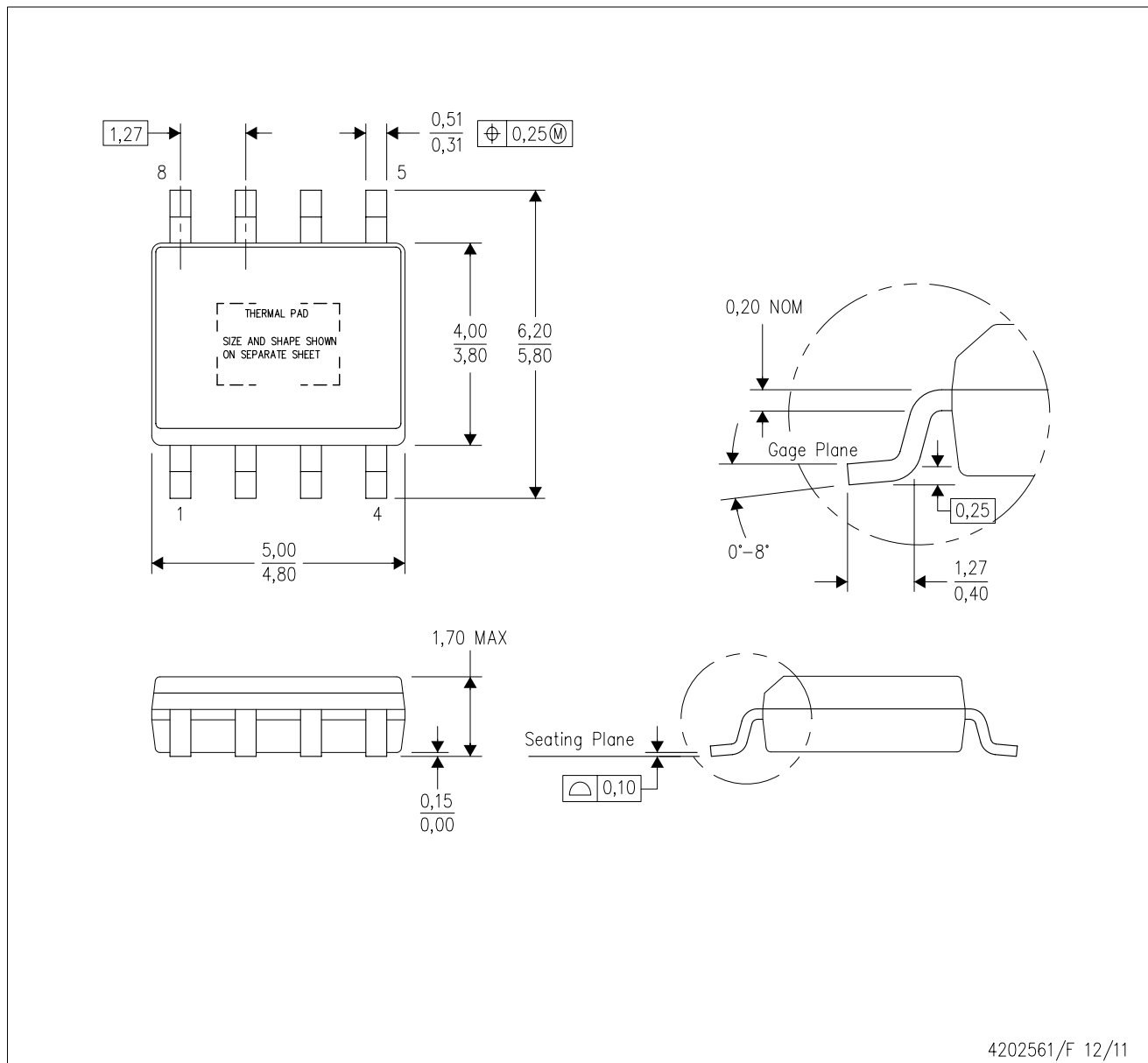
| Device       | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPS54427DDAR | SO PowerPAD  | DDA             | 8    | 2500 | 366.0       | 364.0      | 50.0        |
| TPS54427DRCR | VSON         | DRC             | 10   | 3000 | 367.0       | 367.0      | 35.0        |
| TPS54427DRCT | VSON         | DRC             | 10   | 250  | 210.0       | 185.0      | 35.0        |



Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.

DDA (R-PDSO-G8)

PowerPAD™ PLASTIC SMALL-OUTLINE



- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5-1994.
  - This drawing is subject to change without notice.
  - Body dimensions do not include mold flash or protrusion not to exceed 0,15.
  - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
  - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
  - This package complies to JEDEC MS-012 variation BA

PowerPAD is a trademark of Texas Instruments.

DDA (R-PDSO-G8)

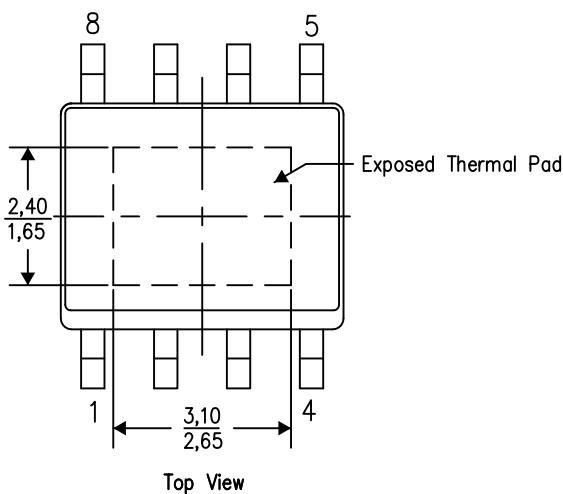
PowerPAD™ PLASTIC SMALL OUTLINE

## THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



Exposed Thermal Pad Dimensions

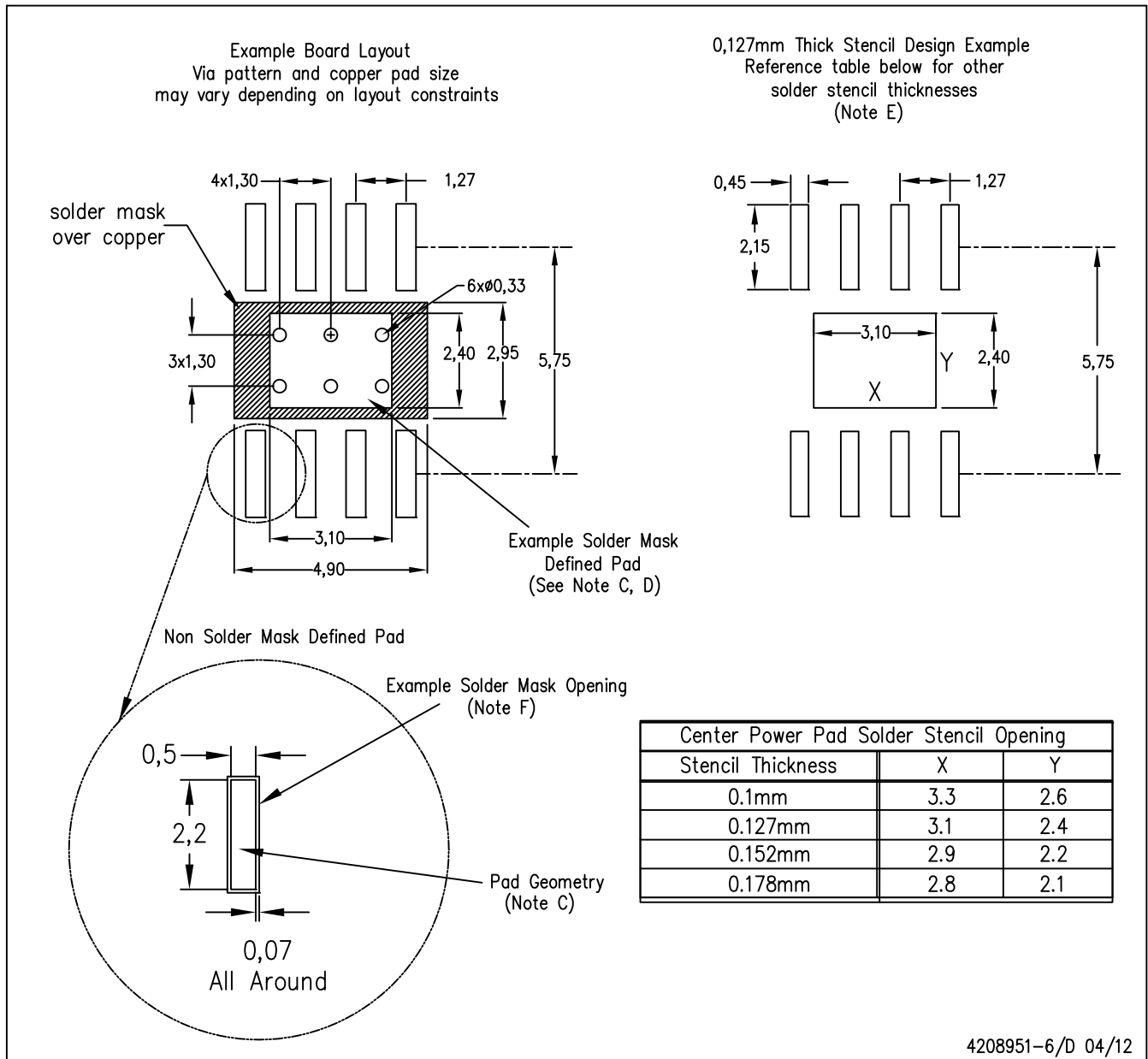
4206322-6/L 05/12

NOTE: A. All linear dimensions are in millimeters

PowerPAD is a trademark of Texas Instruments

DDA (R-PDSO-G8)

PowerPAD™ PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-7351 is recommended for alternate designs.
  - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>. Publication IPC-7351 is recommended for alternate designs.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
  - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

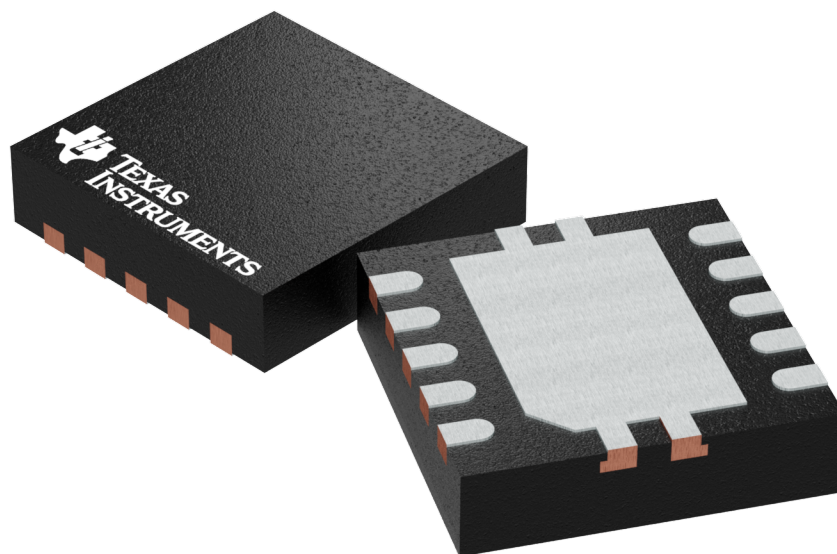
PowerPAD is a trademark of Texas Instruments.

## GENERIC PACKAGE VIEW

DRC 10

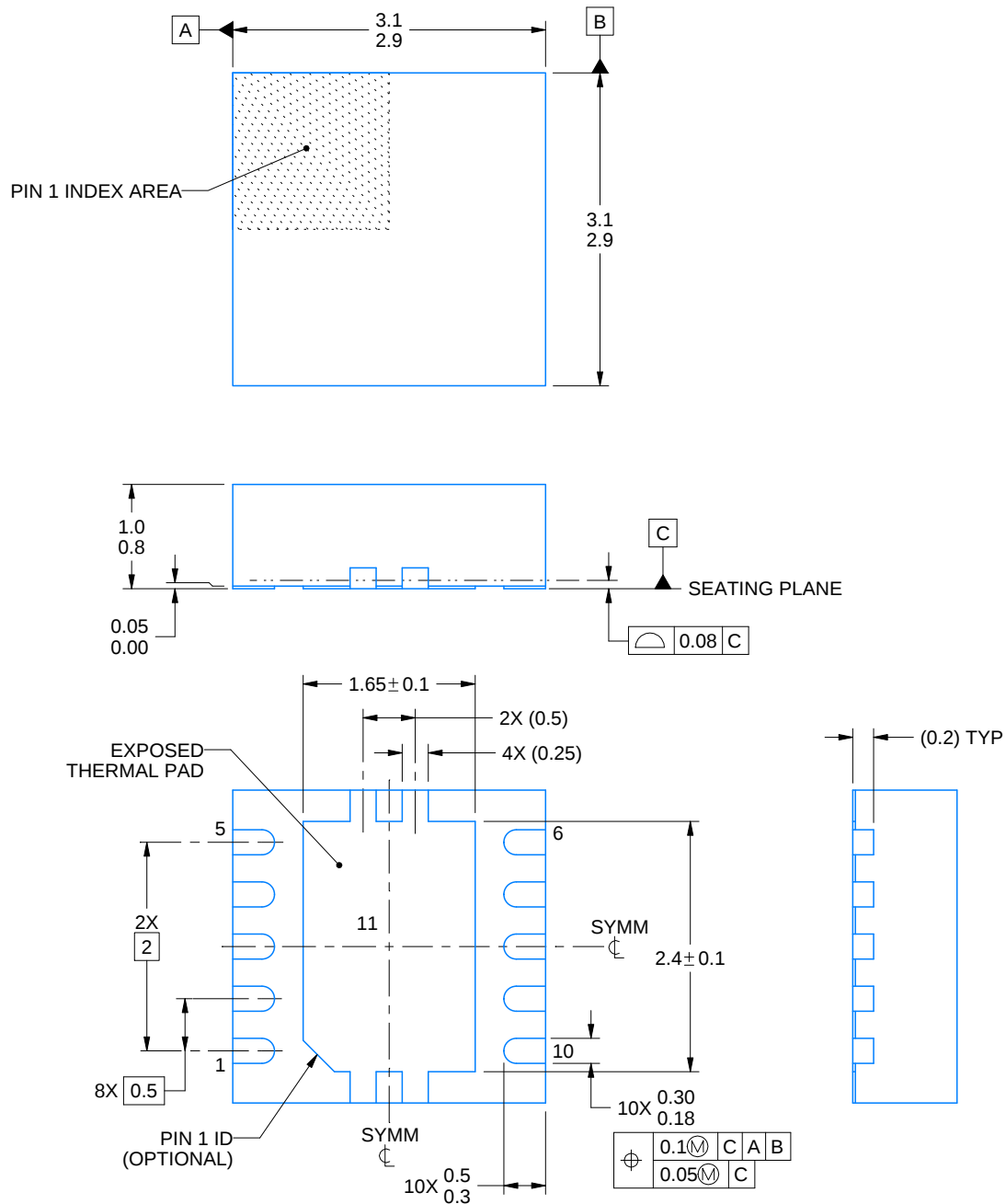
VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.

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4218878/B 07/2018

## NOTES:

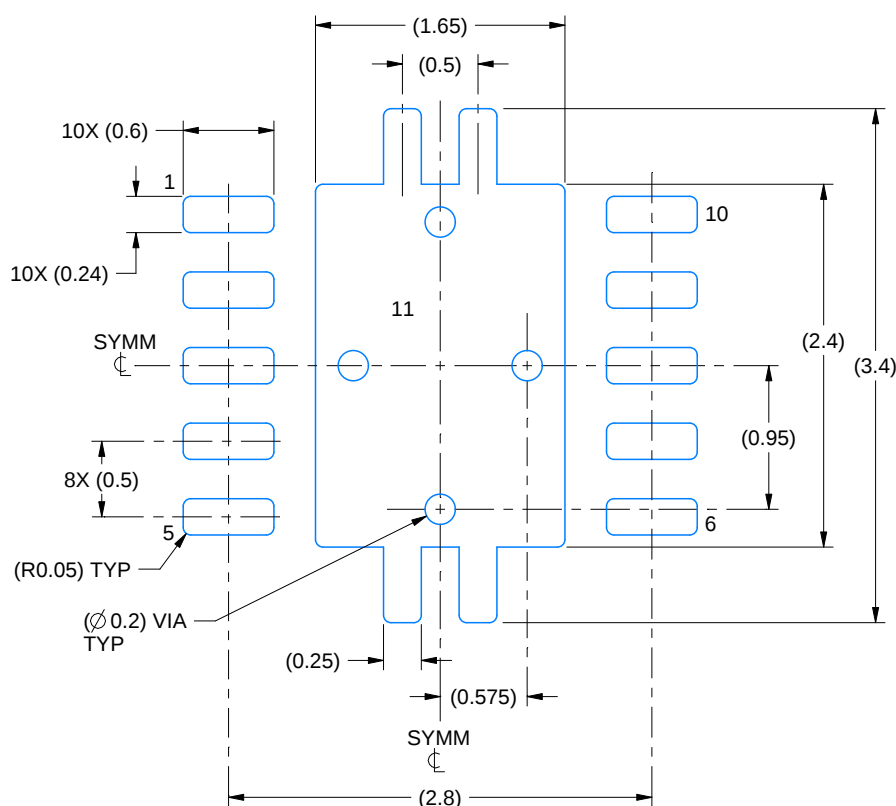
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.

# EXAMPLE BOARD LAYOUT

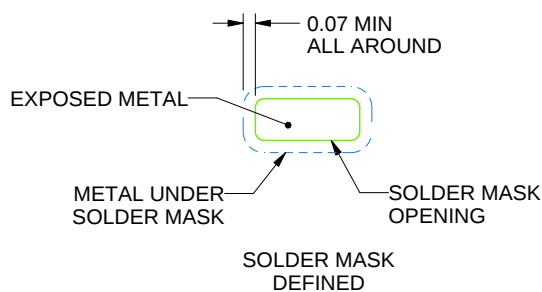
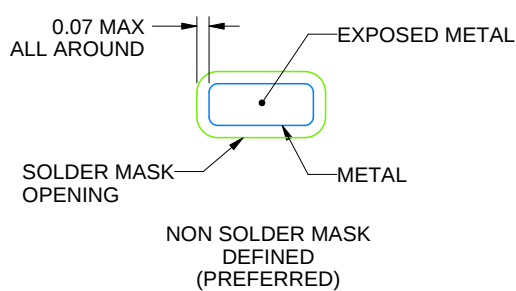
DRC0010J

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:20X



SOLDER MASK DETAILS

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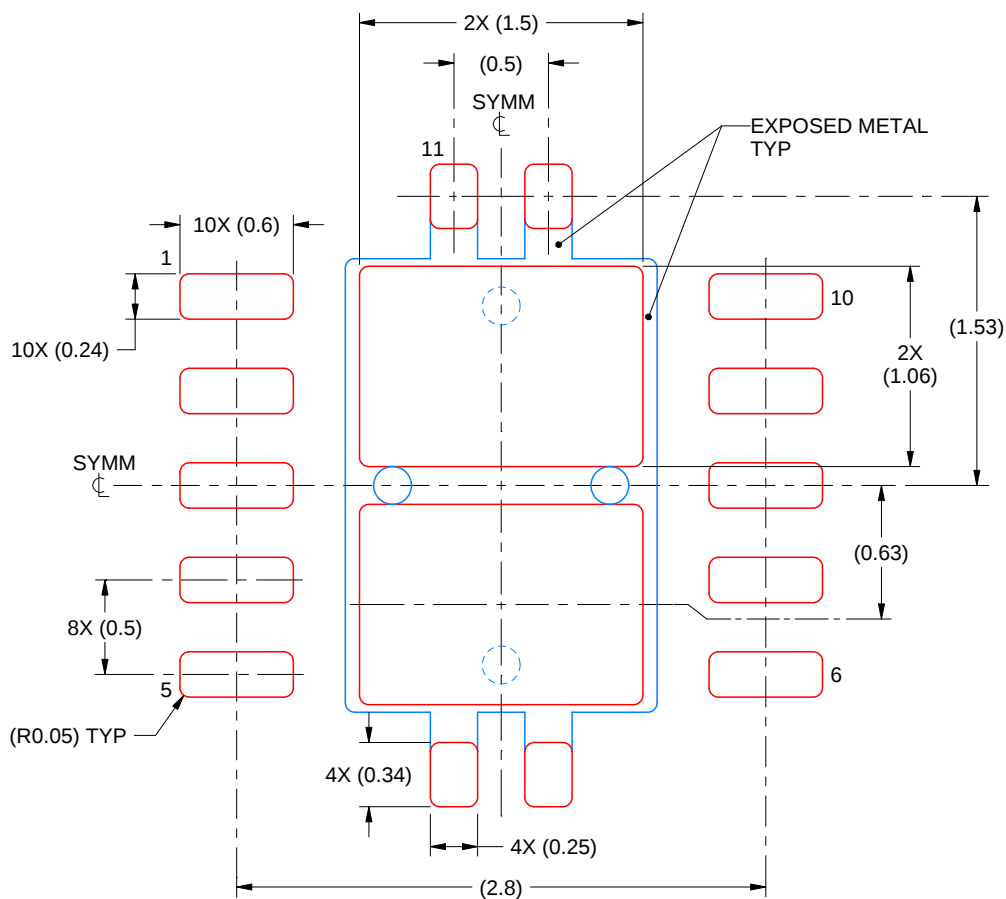
NOTES: (continued)

- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/sluea271](http://www.ti.com/lit/sluea271)).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

**DRC0010J**

**VSON - 1 mm max height**

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 11:  
80% PRINTED SOLDER COVERAGE BY AREA  
SCALE:25X

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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